

International
IR Rectifier

30BQ060

SCHOTTKY RECTIFIER

3 Amp



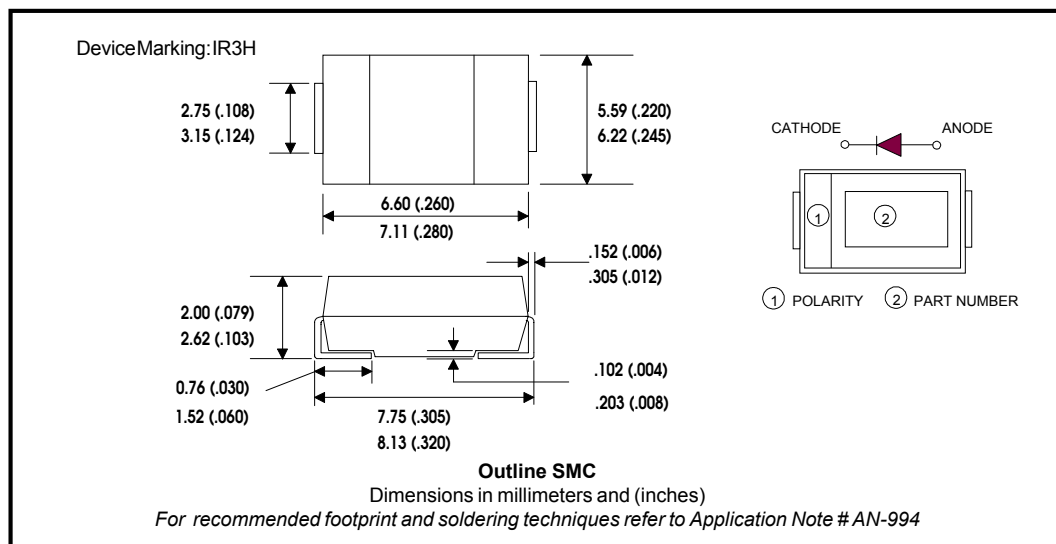
Major Ratings and Characteristics

Characteristics	30BQ060	Units
$I_{F(AV)}$ Rectangular waveform	3.0	A
V_{RRM}	60	V
I_{FSM} @ $t_p = 5 \mu s$ sine	1200	A
V_F @ 3.0Apk, $T_J = 125^\circ C$	0.52	V
T_J range	- 55 to 150	$^\circ C$

Description/Features

The 30BQ060 surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



30BQ060

Bulletin PD-2.440 rev. E 02/02

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Voltage Ratings

Part number	30BQ060
V_R Max. DC Reverse Voltage (V)	60
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	30BQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	3.0	A	50% duty cycle @ $T_L = 123^\circ\text{C}$, rectangular waveform
	4.0		50% duty cycle @ $T_L = 113^\circ\text{C}$, rectangular waveform
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	1200	A	5 μs Sine or 3 μs Rect. pulse
	130		10ms Sine or 6ms Rect. pulse
E_{AS} Non Repetitive Avalanche Energy	6	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 3.4\text{A}$, $L = 10\text{mH}$
I_{AR} Repetitive Avalanche Current	0.6	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_a = 1.5 \times V_r$ typical

Electrical Specifications

Parameters	30BQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1)	0.58	V	@ 3A
	0.76	V	@ 6A
	0.52	V	@ 3A
	0.66	V	@ 6A
I_{RM} Max. Reverse Leakage Current (1)	0.5	mA	$T_J = 25^\circ\text{C}$
	20	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	180	pF	$V_R = 5V_{DC}$ (test signal range 100KHz to 1Mhz) 25°C
L_S Typical Series Inductance	3.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	30BQ	Units	Conditions
T_J Max. Junction Temperature Range (*)	-55 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
R_{thJL} Max. Thermal Resistance Junction to Lead (**)	12	$^\circ\text{C/W}$	DC operation
R_{thJA} Max. Thermal Resistance Junction to Ambient	46	$^\circ\text{C/W}$	DC operation
wt Approximate Weight	0.24(0.008)	g(oz.)	
Case Style	SMC		Similar to DO-214AB
Device Marking	IR3H		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

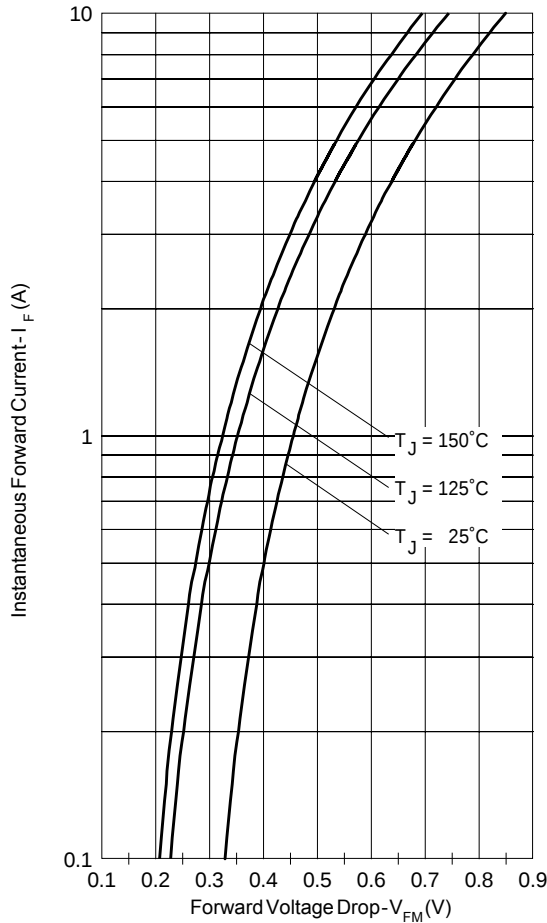


Fig. 1 - Max. Forward Voltage Drop Characteristics (PerLeg)

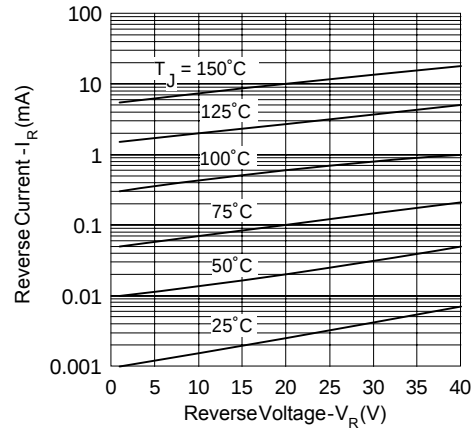


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (PerLeg)

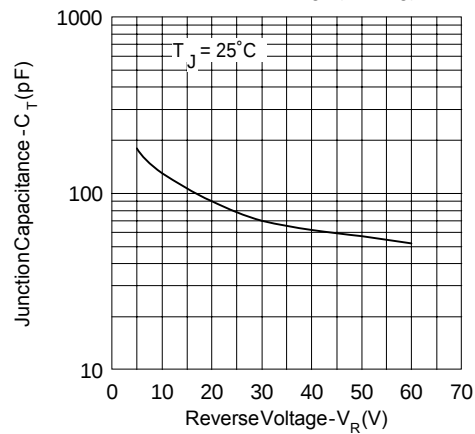


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (PerLeg)

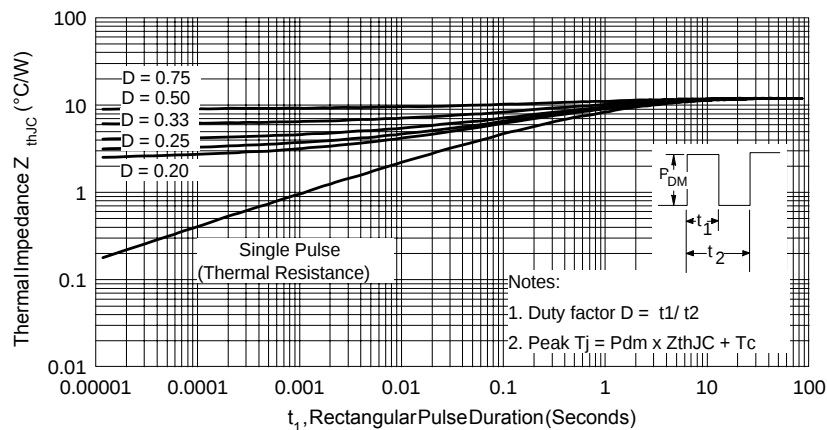


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (PerLeg)

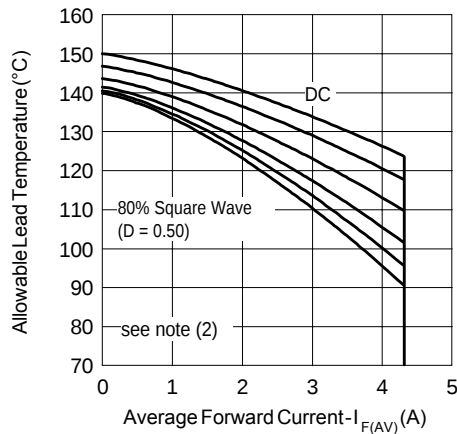


Fig. 4- Maximum Average Forward Current Vs. Allowable Lead Temperature

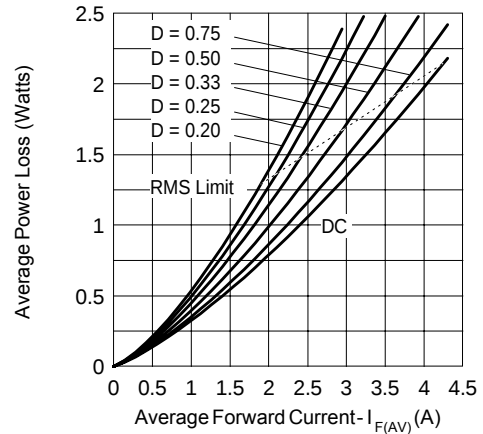


Fig. 5- Maximum Average Forward Dissipation Vs. Average Forward Current

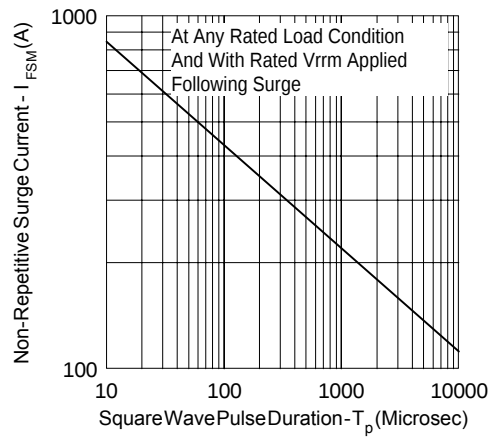


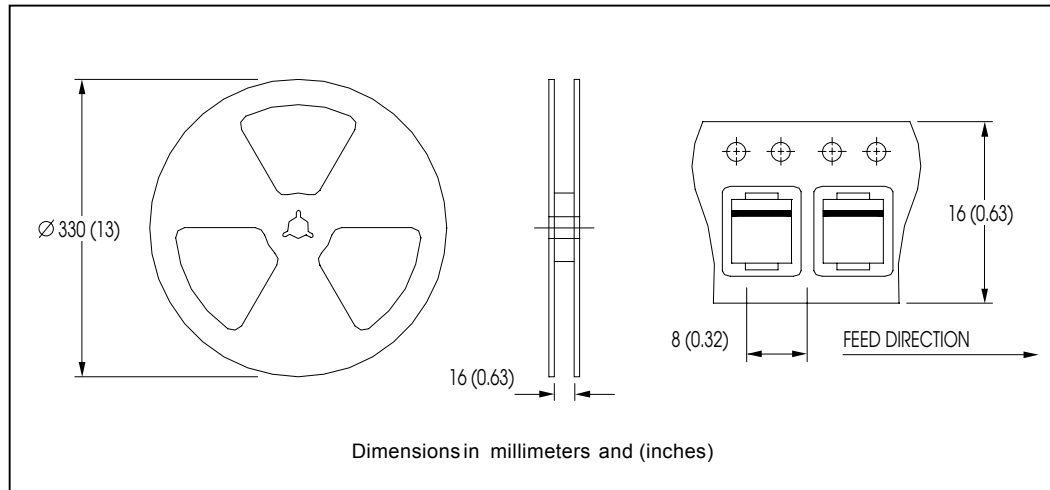
Fig. 6- Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

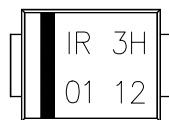
$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

Tape & Reel Information



Marking & Identification

Each device has 8 characters, configured 4 digits on two rows, for identification. The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", and the Part Number (indicates the current rating and voltage/process). The second row indicates the year and the week of manufacturing.



IR 3H

IR logo
 Current Rating (3A)
 Voltage/ Process

C = 15 V
 E = 30 V
 F = 40 V
 H = 60 V
 J = 100 V

YY WW (Date Code)

Year
 Week

Ordering Information

30BQ SERIES - TAPE AND REEL

WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 3000 PIECES).

EXAMPLE: 30BQ060TR - 6000 PIECES

30BQ SERIES - BULK QUANTITIES

WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 1000 PIECES).

EXAMPLE: 30BQ060 - 2000 PIECES

30BQ060

Bulletin PD-2.440 rev. E 02/02

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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